Toshiba Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

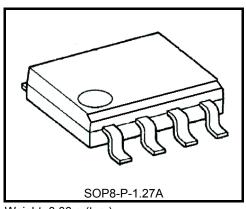
# **TPD1039F**

Low-Side Power Switch for Motor, Solenoid and Lamp Drivers

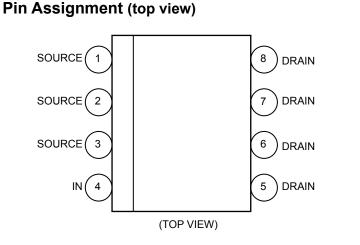
The TPD1039F is a monolithic power IC intended for low-side load switching applications. The output has a vertical MOSFET, and the input can be directly driven from CMOS or TTL logic (e.g., an MPU). The TPD1039F provides intelligent protection functions.

### Features

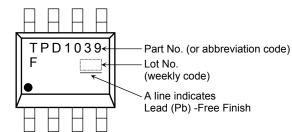
- A structure that incorporates control circuitry and a vertical power MOSFET on a single chip.
- Can be directly driven from a microprocessor, a CMOS logic IC, etc.
- Overvoltage, overtemperature and overcurrent protections
- Low ON-resistance:  $R_{DS}$  (ON) = 0.25  $\Omega$  (max) (@V\_{IN} = 5 V, I\_D = 1 A, T\_{ch} = 25^{\circ}C)
- Housed in the 8-pin SOP package and supplied in embossed carrier tape.



#### Weight: 0.08 g (typ.)



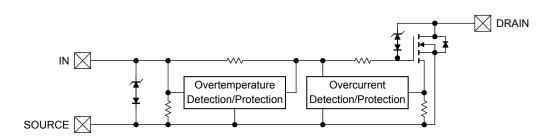
#### Marking



Note: This product has a MOS structure and is sensitive to electrostatic discharge.

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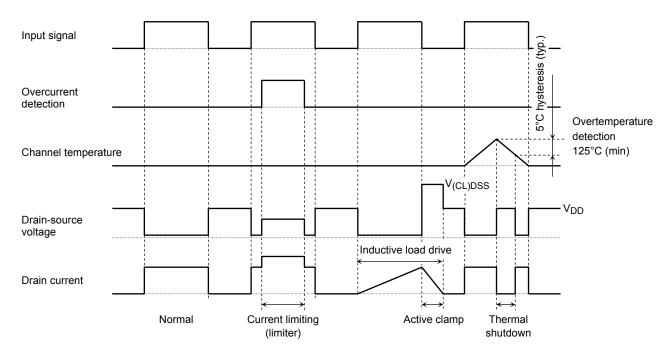
# **Block Diagram**



# **Pin Description**

Pin No.	Symbol	Pin Description
1, 2, 3	SOURCE	Source (ground) pins.
4	IN	Input pin. This pin is connected to a pull-down resistor internally, so that even if the input is open-circuited, the output never turns on inadvertently.
5 ,6, 7, 8	DRAIN	Drain pins. The output current is limited to 5 A (typ.) even if an excessive current flows into a device due to an in-rush current of a lamp or load short-circuit.

# **Timing Chart**



# **Truth Table**

V <sub>IN</sub>	V <sub>DS</sub>	Output State	Operating State		
L	Н	Off	Normal		
Н	L	On	normai		
L	Н	Off	Load short-circuited		
Н	н	Current limiting(limiter)	Load Short-circuited		
L	Н	Off	Overtemperature		
Н	Н	Off	Overtemperature		

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V <sub>DS (DC)</sub>	45	V
Drain current	I <sub>D (DC)</sub>	1.5	А
Input voltage	V <sub>IN</sub>	–0.5 to 6	V
Power dissipation (Note 2-a)	P <sub>D(1)</sub>	1.1	W
Power dissipation (Note 2-b)	P <sub>D(2)</sub>	0.425	W
Single pulse active clamp capability (Note 3)	E <sub>AS</sub>	20	mJ
Active clamp current	I <sub>AR</sub>	1.5	А
Repetitive active clamp capability (Note 2-a) (Note 4)	E <sub>AR</sub>	0.11	mJ
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Channel temperature	T <sub>ch</sub>	150 (Note 5)	°C
Storage temperature	T <sub>stg</sub>	-55 to 150	°C

Note 1: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

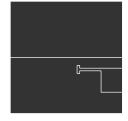
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

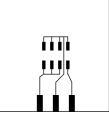
Characteristics	Symbol	Rating	Unit	
	Data a s	113.5 (Note 2-a)	°C /W	
Thermal resistance, channel to ambient	R <sub>th(ch-a)</sub>	294.0 (Note 2-b)		

Note 2:

2-a: glass epoxy board (a)



FR-4 25.4 × 25.4 × 0.8 (unit: mm) 2-b: glass epoxy board (b)



FR-4 25.4 × 25.4 × 0.8 (unit: mm)

Note 3: Active clamp capability (single pulse) test condition

 $V_{DD}$  = 25 V,  $T_{ch}$  = 25°C (initial), L = 10 mH,  $I_{AR}$  = 1.5 A,  $R_G$  = 25  $\Omega$ 

Note 4: Repetitive rating: Pulse width limited by maximum channel temperature

Note 5: Overtemperature protection is tripped at a channel temperature of 125°C. Ensure that the channel temperature, Tch, does not exceed 125°C under the worst-case conditions.

**Electrical Characteristics (T<sub>ch</sub> = 25°C)** 

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Drain-source clamp voltage	V (CL)DSS	-	$V_{IN} = 0 V, I_D = 1 mA$	45	-	-	V	
High-level input voltage	VIH	1	$V_{DS} = 10 \text{ to } 40 \text{ V}, \text{ I}_{D} \ge 1 \text{ A}$ 3.5		-	6	V	
Low-level input voltage	VIL	1	$V_{DS} = 10$ to 40 V, $I_D \leq 10 \mu A$			0.8	V	
Drain cut-off current	$I_{DSS} - V_{IN} = 0 V, V_{DS} = 40 V$		-	-	10	μA		
High-level input current	Ιн	-	$V_{IN} = 5 V$ , at normal operation		-	400	μA	
Drain-source ON-resistance	R <sub>DS(ON)</sub>	-	V <sub>IN</sub> = 5 V, I <sub>D</sub> = 1 A	-	-	0.25	Ω	
Protective circuit operation input Voltage range	V <sub>IN(opr)</sub>	-	-	3.5	-	6	V	
Overtemperature detection (Note 6)	Тот	2	$V_{IN} = 5 V, V_{DD} = 12 V$	125	-	-	°C	
Overcurrent detection	loc	3	V <sub>IN</sub> = 5 V, V <sub>DS</sub> = 24 V	-	5	-	А	
Quitabing times	t <sub>on</sub>	4	$V_{DD} = 24 \text{ V}, \text{ V}_{IN} = 0 \text{ V}/5 \text{ V},$	- 15		-		
Switching times	t <sub>off</sub>		$R_L = 24\Omega$	-	45	-	μS	
Drain-source diode forward Voltage	V <sub>DSF</sub>	-	V <sub>IN</sub> = 0 V, I <sub>DR</sub> = 1.5 A	-	0.9	1.8	v	

Note 6: Overtemperature protection is tripped at a channel temperature of 125°C.

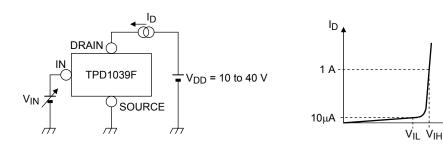
Ensure that the channel temperature, Tch, does not exceed 125°C under the worst-case conditions. This feature is intended to protect the device against damage. The device reliability is not guaranteed if the device persists to remain overtemperature protection mode.

# **Test Circuit 1**

### H-level input voltage, L-level input voltage measuring circuit

#### Test circuit

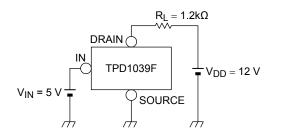
#### Measured waveforms



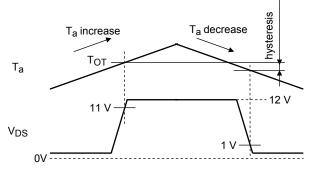
## **Test Circuit 2**

#### Overtemperature detection measuring circuit

Test circuit



#### Measured waveforms

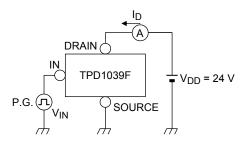


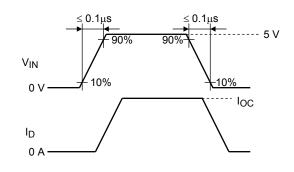
VIN

# **Test Circuit 3**

# **Overcurrent detection circuit**

### Test circuit

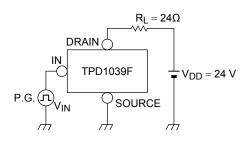




# **Test Circuit 4**

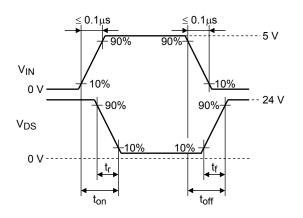
# Switching time measuring circuit

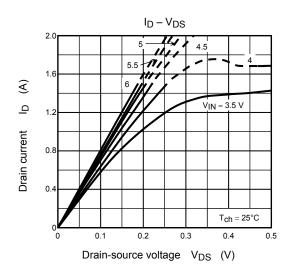
#### Test circuit

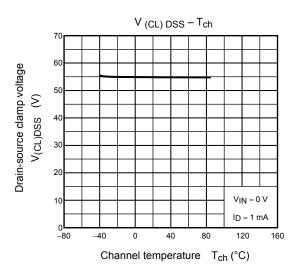


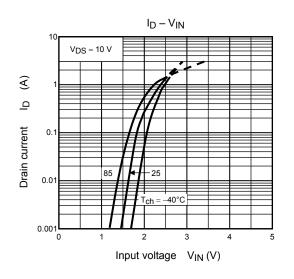
#### Measured waveforms

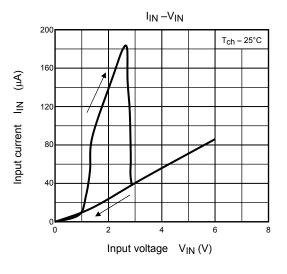
**Measured waveforms** 

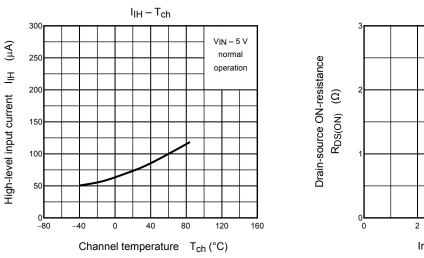


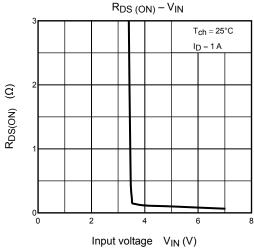


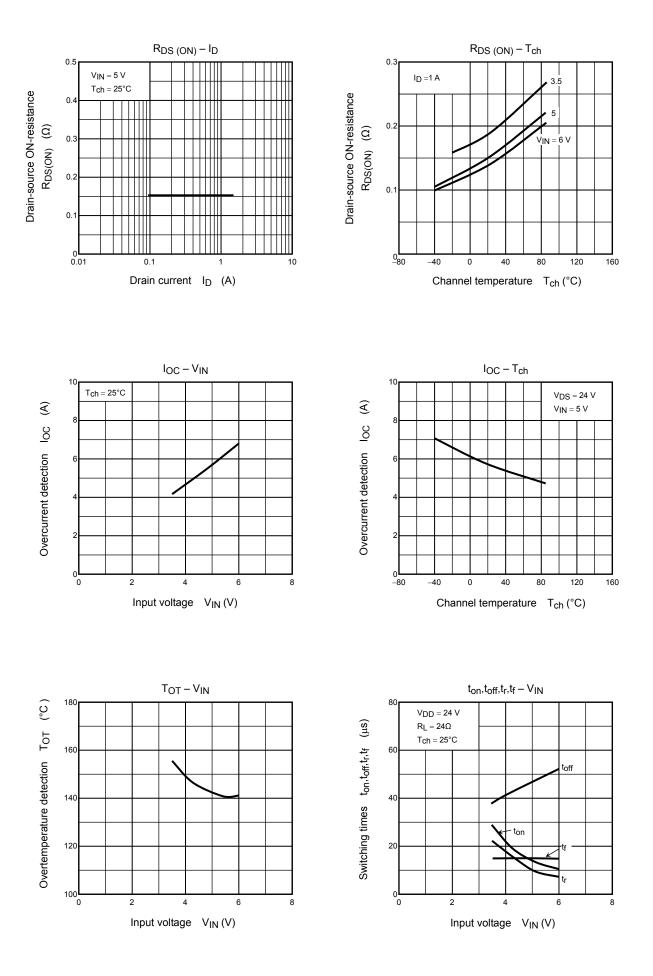


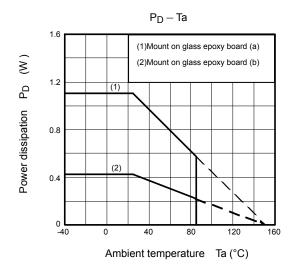


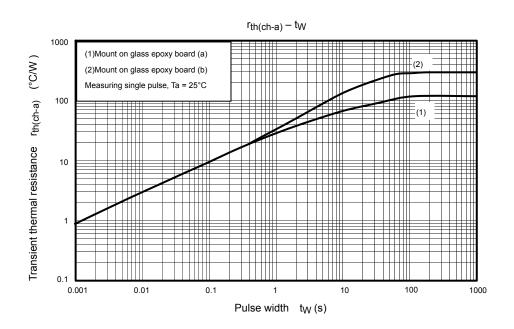




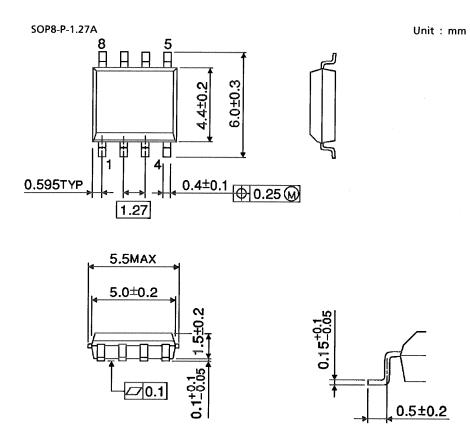








# Package Dimensions



Weight: 0.08 g (typ.)

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20070701-EN GENERAL

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